

## SSR04150S.22 thru SSR04200S.22 and SSR04150-4 thru SSR04200-4

### **Designer's Data Sheet**

### Part Number / Ordering Information<sup>1/</sup>

SSR04

Screening²/ \_ = Not Screened
 TX = TX Level
 TXV = TXV Level
 S = S Level

Package
 S.22 = SMD.22
 S.22C = SMD.22C (Ceramic Lid)
 -4 = LCC4

Voltage 150 = 150 V
 200 = 200 V

# 4 AMP HERMETIC SURFACE MOUNT SCHOTTKY RECTIFIER 150 - 200 VOLTS

#### **FEATURES:**

- Extremely small footprint
- Extremely low forward voltage drop
- Low reverse leakage
- Hermetically sealed surface mount package
- Guard ring for overvoltage protection
- 175°C operating junction temperature
- TX, TXV, and S level screening available consult factory

MAXIMUM RATINGS <sup>3/4/</sup>		Symbol	Value	Unit	
Peak Repetitive Reverse and DC Blocking Voltage	SSR04150 SSR04200	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	150 200	V	
Average Rectified Forward Current (Resistive load, 60 Hz, sine wave, T <sub>A</sub> = 25°C)		lo	4	Α	
<b>Peak Surge Current</b> (8.3 ms pulse, half sine wave superimposed on I <sub>O</sub> , allow junction to reach equilibrium between pulses, T <sub>A</sub> = 25°C)		I <sub>FSM</sub>	50	Α	
Operating & Storage Temperature		T <sub>OP</sub> & T <sub>stg</sub>	-65 to +175	°C	
Maximum Thermal Resistance (Junction to Case)		Rejc	16	°C/W	

NOTES: SMD.22 (S.22) SMD.22C (S.22C) LCC4 (-4)

- 1/ For ordering information, price, and availability contact factory.
- 2/ Screening based on MIL-PRF-19500. Screening flows available on request.
- 3/ Unless otherwise specified, all electrical characteristics @ 25°C.
- 4/ SMD.22: For optimal performance, connect anode terminals together.
  - LCC4: For optimal performance, connect anode terminals together and cathode terminals together.
- 5/ Pulsed per MIL-STD-750.
- 6/ For SMD.22C (Ceramic Lid) Package Height = .070" ± .010"







(dime used for size reference)

**NOTE:** All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: SH0073D

**DOCX** 



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# SSR04150S.22 thru SSR04200S.22 and SSR04150-4 thru SSR04200-4

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ELECTRICAL CHARACTERISTICS 4/5/		Symbol	Min	Тур	Max	Unit
Instantaneous Forward Voltage Drop (T <sub>A</sub> = 25°C, pulsed)	I <sub>F</sub> = 0.1 A	$V_{F1}$	-	0.57	-	
	$I_F = 0.5 A$	$V_{F2}$	-	0.72	0.80	V <sub>DC</sub>
	I <sub>F</sub> = 1 A	<b>V</b> F3	-	0.77	0.85	
	I <sub>F</sub> = 2 A	V <sub>F4</sub>	-	0.84	-	
	I <sub>F</sub> = 4 A	V <sub>F5</sub>	-	0.92	1.00	
Instantaneous Forward Voltage Drop (T <sub>A</sub> = -55°C, pulsed)	$I_F = 1 A$	$V_{F6}$	-	0.92	-	
	$I_F = 2 A$	$V_{F7}$	-	1.11	-	V <sub>DC</sub>
	$I_F = 4 A$	$V_{F8}$	-	1.45	-	
Instantaneous Forward Voltage Drop (T <sub>A</sub> = 125°C, pulsed)	I <sub>F</sub> = 0.1 A	<b>V</b> <sub>F11</sub>	-	0.43	_	<b>V</b> <sub>DC</sub>
	$I_F = 0.5 A$	$V_{\text{F12}}$	-	0.56	0.65	
	$I_F = 1 A$	$V_{F13}$	-	0.62	0.71	
	$I_F = 2 A$	$V_{\text{F14}}$	-	0.70	-	
	$I_F = 4 A$	<b>V</b> F15	-	0.79	0.88	
Reverse Leakage Current (Rated V <sub>R</sub> , T <sub>A</sub> = 25°C, pulsed)		I <sub>R1</sub>	-	0.15	2	μΑ
Reverse Leakage Current (Rated V <sub>R</sub> , T <sub>A</sub> = 100°C, pulsed)		I <sub>R2</sub>	-	30	-	μΑ
Reverse Leakage Current (Rated V <sub>R</sub> , T <sub>A</sub> = 125°C, pulsed)		I <sub>R3</sub>	-	150	200	μΑ
Reverse Leakage Current (Rated V <sub>R</sub> , T <sub>A</sub> = 150°C, pulsed)		I <sub>R4</sub>	-	600	-	μΑ
Junction Capacitance (f = 1 MHz, T <sub>A</sub> = 25°C)	$V_R = 5 V$ $V_R = 10 V$	C₁	-	40 30	- 40	pF

